

## Description

The 74AHC1G125Q is an automotive compliant single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable (OE) pin. The device is designed for operation with a power supply range of 2.0V to 5.5V.

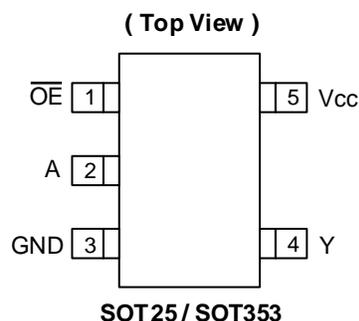
## Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 2.0V to 5.5V
- ±8mA Output Drive at 4.5V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by V<sub>CC</sub>
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The 74AHC1G125Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Assignments



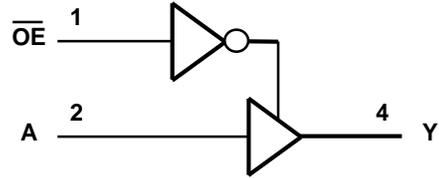
## Applications

- General Purpose Logic
- Wide Array of Products, such as:
  - Automotive Applications within Grade 1 Temperature Range
  - Industrial Computing/Controls/Automation
  - High Reliability Networking/Communications
  - Industrial/Agricultural Equipment

**Pin Descriptions**

Pin Name	Description
OE	Output Enable
A	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

**Logic Diagram**



**Function Table**

Inputs		Output
OE	A	Y
L	H	H
L	L	L
H	X	Z

**Absolute Maximum Ratings** (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
Vi	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
Iik	Input Clamp Current Vi < 0	-20	mA
Iok	Output Clamp Current (Vo < 0 or Vo > Vcc)	±20	mA
Io	Continuous Output Current (Vo = 0 to Vcc)	±25	mA
Icc	Continuous Current Through Vcc	75	mA
Ignd	Continuous Current Through GND	-75	mA
Tj	Operating Junction Temperature	-40 to +150	°C
Tstg	Storage Temperature	-65 to +150	°C
Pd	Total Power Dissipation (Note 6)	250	mW

- Notes:
- Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
  - Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.
  - This will need to be derated at higher operating temperatures to prevent exceeding maximum Tj. Refer to package thermal characteristics section.

**Recommended Operating Conditions** (Note 7)

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Operating Voltage	—	2	5.5	V
V <sub>IH</sub>	High-Level Input Voltage	V <sub>CC</sub> = 2V	1.5	—	V
		V <sub>CC</sub> = 3V	2.1	—	
		V <sub>CC</sub> = 5.5V	3.85	—	
V <sub>IL</sub>	Low-Level Input Voltage	V <sub>CC</sub> = 2V	—	0.5	V
		V <sub>CC</sub> = 3V	—	0.9	
		V <sub>CC</sub> = 5.5V	—	1.65	
V <sub>I</sub>	Input Voltage	—	0	5.5	V
V <sub>O</sub>	Output Voltage	—	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-Level Output Current	V <sub>CC</sub> = 2V	—	-50	μA
		V <sub>CC</sub> = 3.3V ± 0.3V	—	-4	mA
		V <sub>CC</sub> = 5V ± 0.5V	—	-8	
I <sub>OL</sub>	Low-Level Output Current	V <sub>CC</sub> = 2V	—	50	μA
		V <sub>CC</sub> = 3.3V ± 0.3V	—	4	mA
		V <sub>CC</sub> = 5V ± 0.5V	—	8	
Δt/ΔV	Input Transition Rise or Fall Rate	V <sub>CC</sub> = 3.3V ± 0.3V	—	100	ns/V
		V <sub>CC</sub> = 5V ± 0.5V	—	20	
T <sub>A</sub>	Operating Free-Air Temperature	—	-40	+125	°C

Note: 7. Unused inputs should be held at V<sub>CC</sub> or Ground.

**Electrical Characteristics** (All typical values are at V<sub>CC</sub> = 3.3V, T<sub>A</sub> = +25°C.)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V <sub>OH</sub>	High Level Output Voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> = -50μA	2V	1.9	2	—	1.9	—	1.9	—	V
			3V	2.9	3	—	2.9	—	2.9	—	
			4.5V	4.4	4.5	—	4.4	—	4.4	—	
V <sub>OL</sub>	Low Level Output Voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> = 50μA	2V	—	—	0.1	—	0.1	—	0.1	V
			3V	—	—	0.1	—	0.1	—	0.1	
			4.5V	—	—	0.1	—	0.1	—	0.1	
V <sub>OL</sub>	Low Level Output Voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> = 4mA	3V	—	—	0.36	—	0.44	—	0.55	V
			4.5V	—	—	0.36	—	0.44	—	0.55	
I <sub>OZ</sub>	Z State Leakage Current	V <sub>I</sub> = 5.5V or GND V <sub>O</sub> = 0 to 5.5V	5.5V	—	—	0.25	—	2.5	—	10	μA
I <sub>I</sub>	Input Current	V <sub>I</sub> = 5.5V or GND	0 to 5.5V	—	—	±0.1	—	±1	—	±2	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0	5.5V	—	—	1	—	10	—	40	μA
C <sub>I</sub>	Input Capacitance	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5V	—	2.0	10	—	10	—	10	pF

## Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
$\theta_{JA}$	Thermal Resistance Junction-to-Ambient	SOT25	Note 8	—	184	—	°C/W
		SOT353		—	385	—	
$\theta_{JC}$	Thermal Resistance Junction-to-Case	SOT25	Note 8	—	62	—	°C/W
		SOT353		—	164	—	

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

## Switching Characteristics

V<sub>CC</sub> = 3.3V ± 0.3V (See Figure 1)

Parameter	From (Input)	To (Output)	Test Conditions	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PD</sub>	A	Y	C <sub>L</sub> = 15pF	1.0	4.7	8.0	1.0	9.5	1.0	11.5	ns
			C <sub>L</sub> = 50pF	1.0	6.6	11.5	1.0	13.0	1.0	14.5	ns
t <sub>EN</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.0	5.0	8.0	1.0	9.5	1.0	11.5	ns
			C <sub>L</sub> = 50pF	1.0	6.9	11.5	1.0	13.0	1.0	14.5	ns
t <sub>DIS</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.0	6.0	9.7	1.0	11.5	1.0	12.5	ns
			C <sub>L</sub> = 50pF	1.0	8.3	13.2	1.0	15.0	1.0	16.5	ns

V<sub>CC</sub> = 5V ± 0.5V (See Figure 1)

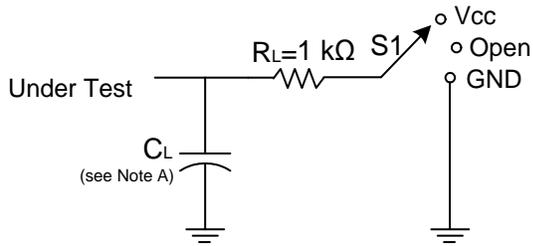
Parameter	From (Input)	To (Output)	Test Conditions	+25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PD</sub>	A	Y	C <sub>L</sub> = 15pF	1.0	3.4	5.5	1.0	6.5	1.0	7.0	ns
			C <sub>L</sub> = 50pF	1.0	4.8	7.5	1.0	8.5	1.0	9.5	ns
t <sub>EN</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.0	3.6	5.1	1.0	6.0	1.0	6.5	ns
			C <sub>L</sub> = 50pF	1.0	4.9	7.5	1.0	8.5	1.0	9.5	ns
t <sub>DIS</sub>	$\overline{OE}$	Y	C <sub>L</sub> = 15pF	1.0	4.1	6.8	1.0	8.0	1.0	8.5	ns
			C <sub>L</sub> = 50pF	1.0	5.7	8.8	1.0	10.0	1.0	11.0	ns

## Operating Characteristics

T<sub>A</sub> = +25°C

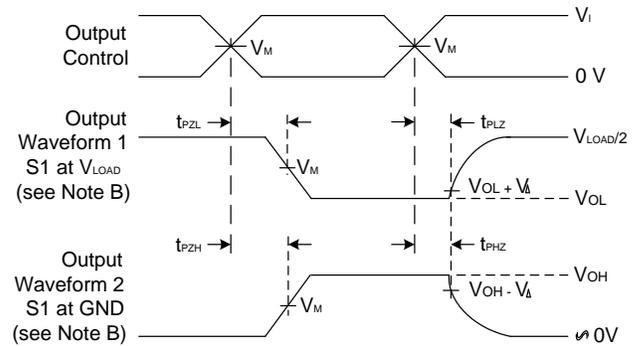
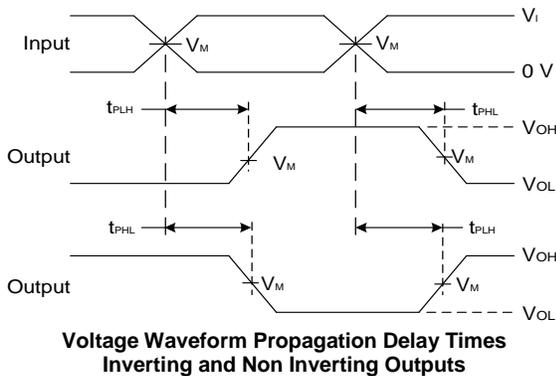
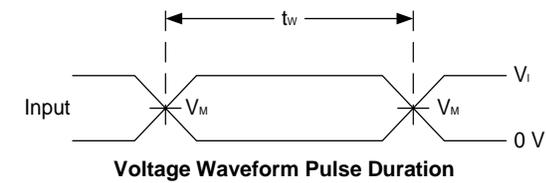
Parameter	Test Conditions	V <sub>CC</sub> = 5V	Unit
		Typ	
C <sub>PD</sub>	f = 1MHz No Load	10	pF

**Measurement Information**



Test	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

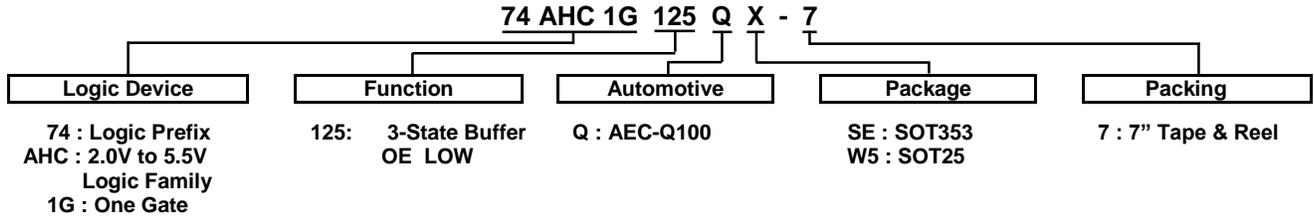
Vcc	Inputs		Vm	CL	VΔ
	Vi	tR/tF			
3.3V±0.3V	Vcc	≤3ns	Vcc/2	15pF	0.3V
5V±0.5V	Vcc	≤3ns	Vcc/2	15pF	0.3V
3.3V±0.3V	Vcc	≤3ns	Vcc/2	50pF	0.3V
5V±0.5V	Vcc	≤3ns	Vcc/2	50pF	0.3V



**Figure 1. Load Circuit and Voltage Waveforms**

- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
  - C. Inputs are measured separately one transition per measurement.
  - D.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{DIS}$ .
  - E.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN}$ .
  - F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .

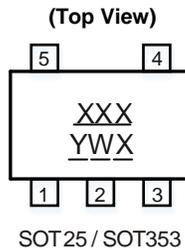
## Ordering Information (Note 9)



Part Number	Package Code	Package (Notes 10 & 11)	Package Size	7" Tape and Reel	
				Quantity	Part Number Suffix
74AHC1G125QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7
74AHC1G125QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm lead pitch	3000/Tape & Reel	-7

Notes: 9. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.  
 10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at <http://www.diodes.com/package-outlines.html>.  
 11. The taping orientation is located on our website at <https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf>.

## Marking Information



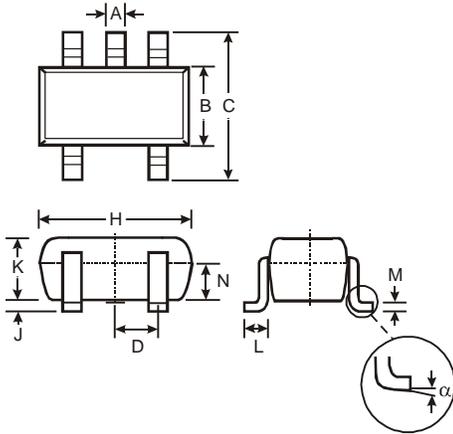
**XXX** : Identification Code  
**Y** : Year 0~9  
**W** : Week: A~Z 1~26 week  
           a~z 27~52 week  
           z represents week 52 and 53  
**X** : A~ Z: Internal Code

Part Number	Package	Identification Code
74AHC1G125QW5-7	SOT25	YYQ
74AHC1G125QSE-7	SOT353	YYQ

## Package Outline Dimensions

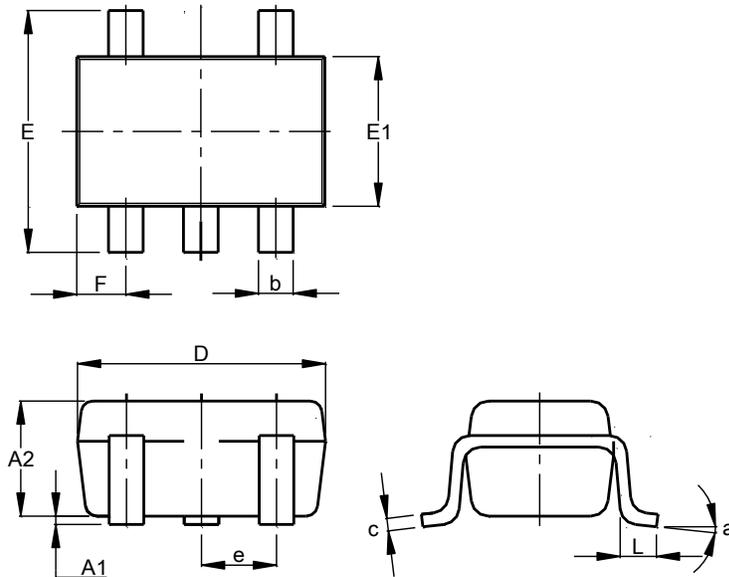
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SOT25



SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	-	-	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All Dimensions in mm			

### (2) Package Type: SOT353

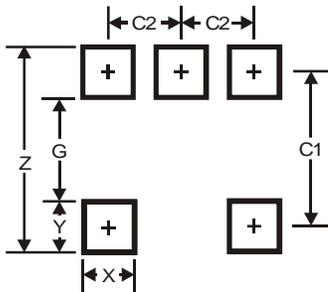


SOT353			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

## Suggested Pad Layout

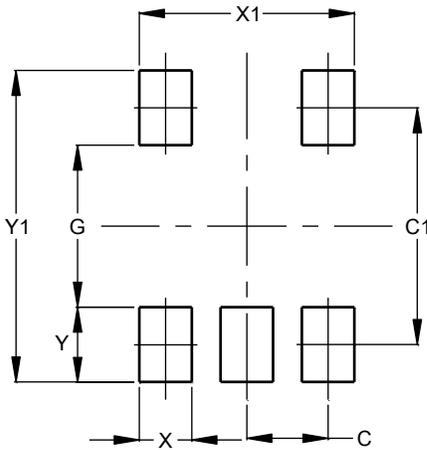
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

### (2) Package Type: SOT353



Dimensions	Value (in mm)
C	0.650
C1	1.900
G	1.300
X	0.420
X1	1.720
Y	0.600
Y1	2.500

## Mechanical Data

### SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>Ⓔ</sup>
- Weight: 0.0158 grams (Approximate)

### SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>Ⓔ</sup>
- Weight: 0.0064 grams (Approximate)

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